

Silicon NPN Power Transistors

2SC2553

DESCRIPTION

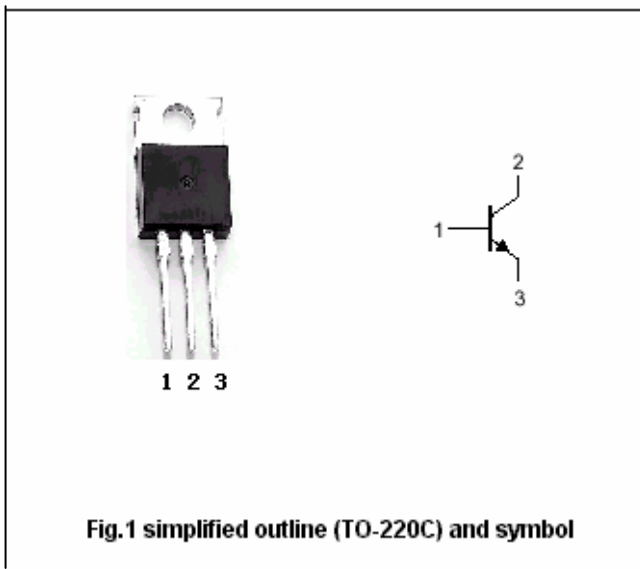
- With TO-220C package
- High collector breakdown voltage
: $V_{CEO}=400V(\text{Min})$
- Excellent switching time
: $t_r=1.0\mu s(\text{Max.})$
: $t_f=1.0\mu s(\text{Max.}@I_C=4A)$

APPLICATIONS

- Switching regulator and high voltage switching applications
- High speed DC-DC converter applications

PINNING

PIN	DESCRIPTION
1	Base
2	Collector;connected to mounting base
3	Emitter



Absolute maximum ratings($T_a=25^\circ C$)

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V_{CBO}	Collector-base voltage	Open emitter	500	V
V_{CEO}	Collector-emitter voltage	Open base	400	V
V_{EBO}	Emitter-base voltage	Open collector	7	V
I_C	Collector current		5	A
I_B	Base current		1	A
P_C	Collector dissipation	$T_a=25^\circ C$	1.5	W
		$T_C=25^\circ C$	40	
T_j	Junction temperature		150	$^\circ C$
T_{stg}	Storage temperature		-55~150	$^\circ C$

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CHARACTERISTICS

T_j=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C =10mA ; I _B =0	400			V
V _{(BR)CBO}	Collector-base breakdown voltage	I _C =1mA ; I _E =0	500			V
V _{CEsat}	Collector-emitter saturation voltage	I _C =5A; I _B =1A			1.0	V
V _{BEsat}	Base-emitter saturation voltage	I _C =5A; I _B =1A			1.5	V
I _{CBO}	Collector cut-off current	V _{CB} =400V ; I _E =0			100	μA
I _{EBO}	Emitter cut-off current	V _{EB} =7V; I _C =0			1	mA
h _{FE-1}	DC current gain	I _C =3A ; V _{CE} =5V	12			
h _{FE-2}	DC current gain	I _C =5A ; V _{CE} =5V	8			

Switching times

t _r	Rise time	V _{CC} ≈200V; I _C =4A I _{B1} =-I _{B2} =0.4A; R _L =50Ω Duty cycle≤1%			1.0	μs
t _{stg}	Storage time				2.5	μs
t _f	Fall time				1.0	μs

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PACKAGE OUTLINE

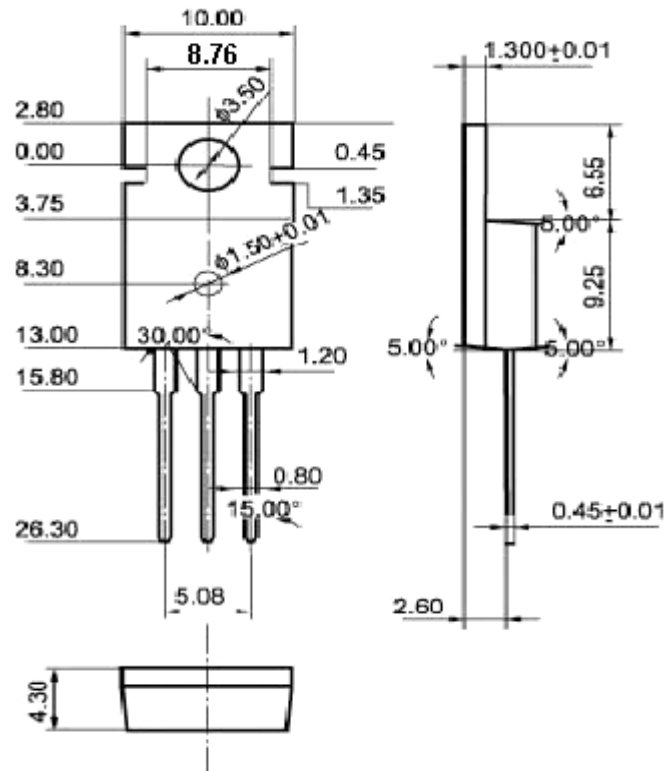


Fig.2 Outline dimensions (unindicated tolerance:±0.10 mm)

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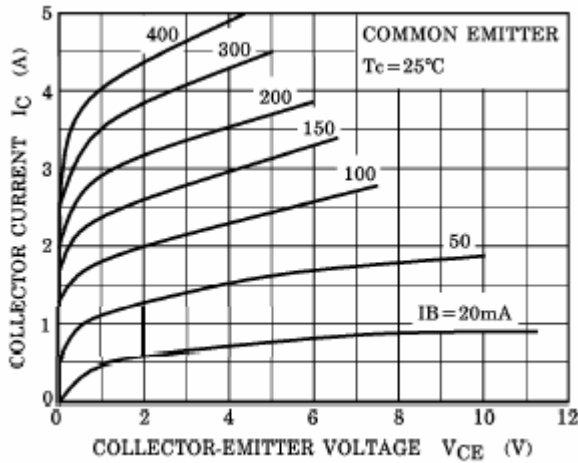


Fig.3 Static Characteristic

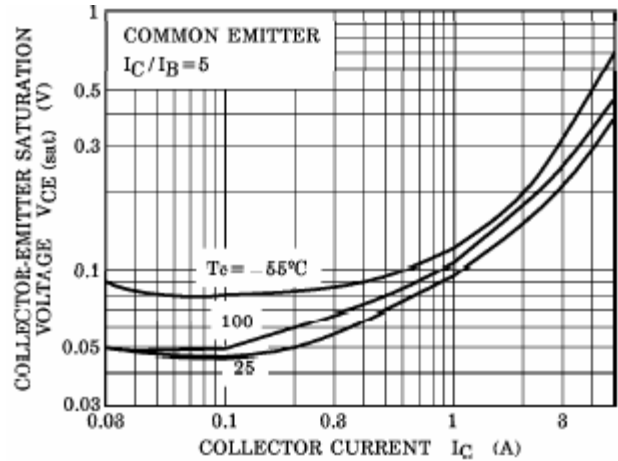


Fig.4 Collector-Emitter Saturation Voltage

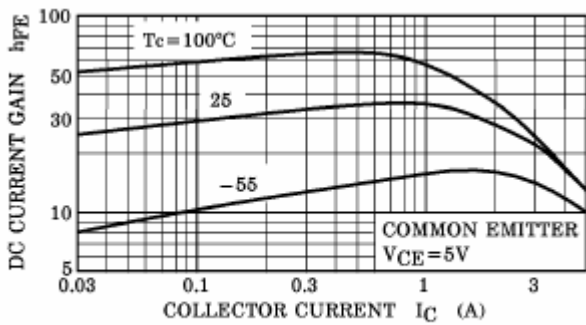


Fig.5 DC current Gain

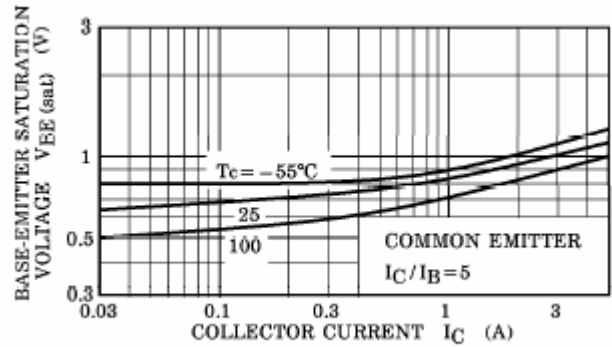


Fig.6 Base-Emitter Saturation Voltage

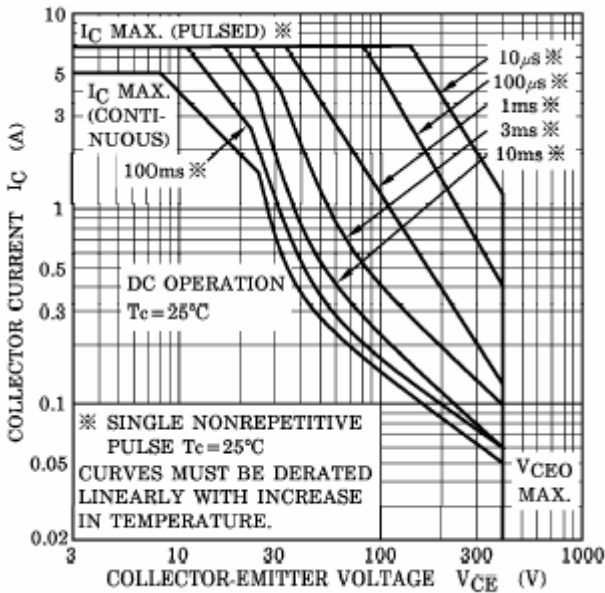


Fig.7 Safe Operating Area